



ORIENT

Photo coupler

Product Data Sheet

Part Number: OR-3H4-4

Customer: _____

Date: _____

一级代理商：

深圳市弗瑞鑫电子有限公司

地址：深圳市宝安区西乡大道302号金源商务大厦B座三楼

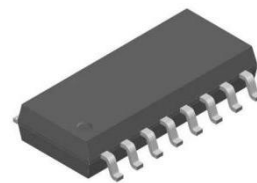
TEL: 0755-29563634

FAX: 0755-27447020

www.frxelec.com

1. Features

- (1) Current transfer ratio(CTR) : MIN. 20% (at $I_F = \pm 1\text{mA}$, $V_{CE} = 5\text{V}$, $T_a = 25^\circ\text{C}$)
- (2) High input-output isolation voltage.($V_{ISO} = 3,750\text{Vrms}$)
- (3) $BV_{CEO} = 80\text{V(MIN)}$
- (4) Operating temperature: -55°C to 125°C
- (5) In compliance with RoHS, REACH standards
- (6) ESD pass HBM 8000V/MM 2000V
- (7) Safety approval
 - UL approved (No.E323844)
 - VDE approved (No.40029733)
- (8) MSL Class I



2. Instructions

The OR-3H4-4 series is consist of four channel device each pair contains two infrared led and a photo transistor detector. They are encapsulated in a 16-pin SOP, free of halogens and Sb2O3

3. Application Range

- (1) Hybrid substrates that require high density mounting
- (2) Programmable controller
- (3) System apparatus, measuring instruments

4. Max Absolute rated Value (Normal Temperature=25°C)

Parameter		Symbol	Rated Value	Unit
Input	Forward Current	I_F	50	mA
	Peak forward current($t=10\mu\text{s}$)	I_{FM}	1	A
	Reverse Voltage	V_R	6	V
	Power Dissipation	P	65	mW
	Junction Temperature	T_j	125	$^\circ\text{C}$
Output	Collector and emitter Voltage	V_{CEO}	80	V
	Emitter and collector Voltage	V_{ECO}	7	
	Collector Current	I_C	50	mA
	Power Dissipation	P_C	150	mW
	Junction Temperature	T_j	125	$^\circ\text{C}$
Total Power Dissipation		P_{tot}	200	mW
*1 Insulation Voltage		V_{iso}	3750	Vrms
Operating Temperature		T_{opr}	-55 to +125	$^\circ\text{C}$
Storage Temperature		T_{stg}	-55 to +150	
*2 Soldering Temperature		T_{sol}	260	

*1. AC For 1 Minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2.soldering time is 10 seconds.

5. Opto-electronic Characteristics(Normal Temperature=25°C)

Parameter		Symbol	Min	Typ.*	Max	Unit	Condition
Input	Forward Voltage	V_F	---	1.2	1.4	V	$I_F=\pm 20\text{mA}$
	Terminal Capacitance	C_t	---	60	---	pF	$V=0, f=1\text{KHz}$
Output	Collector Dark Current	I_{CEO}	---	---	100	nA	$V_{CE}=20\text{V}, I_F=0\text{mA}$
	Collector-Emitter Breakdown Voltage	BV_{CEO}	80	---	---	V	$I_C=0.1\text{mA}, I_F=0\text{mA}$
	Emitter-Collector Breakdown Voltage	BV_{ECO}	7	---	---	V	$I_E=0.1\text{mA}, I_F=0\text{mA}$
	*1 Current Transfer Ratio	CTR	20	---	400	%	$I_F=\pm 1\text{mA}$ $V_{CE}=5\text{V}$
	Collector Current	I_C	2	---	40	mA	
Transforming Characteristics	Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	---	---	0.4	V	$I_F=\pm 8\text{mA}$ $I_C=2.4\text{mA}$
	Insulation Impedance	R_{iso}	5×10^{10}	1×10^{11}	---	Ω	DC 500V 40~60%R.H.
	Floating Capacitance	C_f	---	0.8	1	pF	$V=0, f=1\text{MHz}$
	Response Time	t_r	---	3	18	μs	$V_{CE}=10\text{V},$ $I_C=2\text{mA},$ $R_L=100\Omega,$ $f=100\text{Hz}$
	Descend Time	t_f	---	4	18	μs	

- Current Conversion Ratio = $I_C / I_F \times 100\%$

6. Rank table of current transfer ratio CTR

MODEL NO.	CTR Rank	Min.	Max.	Condition	Unit
OR-3H4-4	NO mark	20	400	IF=±1mA, V _{CE} =5V, Ta=25°C	%
	A5	100	300		
	B3	150	300	IF=±5mA, V _{CE} =5V, Ta=25°C	
	GB	100	400	IF=±5mA, V _{CE} =5V, Ta=25°C	

- Current Conversion Ratio = $I_C / I_F \times 100\%$

7. Order Information

Part Number

OR-3H4-4X-W-Y-Z

Note

X = CTR Rank (A5 , B3 , GB or none)

W = Tape and reel option (TA or TA1).

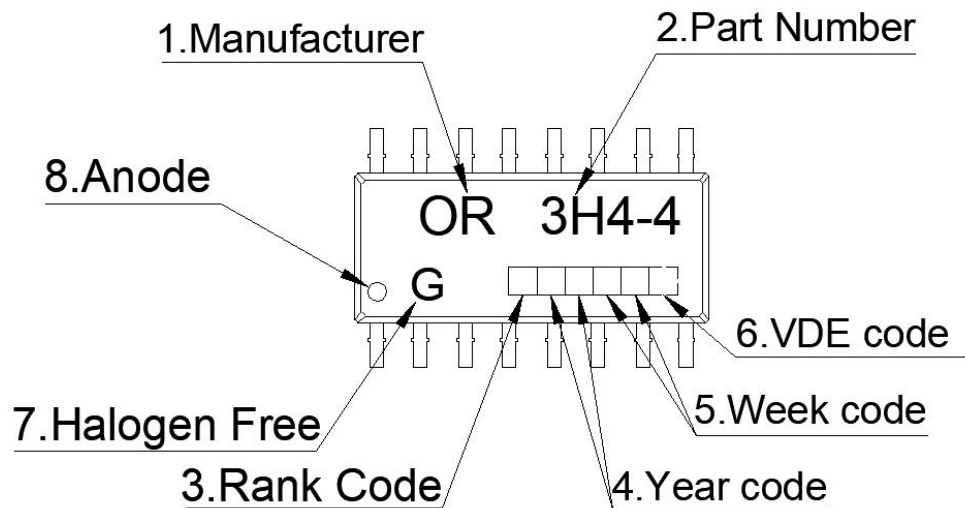
Y = 'V' code for VDE safety (This options is not necessary).

Z = 'G' code for Halogen free .

* VDE Code can be selected.

Option	Description	Packing quantity
TA	Surface mount lead form (low profile) + TA tape & reel option	2000 units per reel
TA1	Surface mount lead form (low profile) + TA1 tape & reel option	2000 units per reel

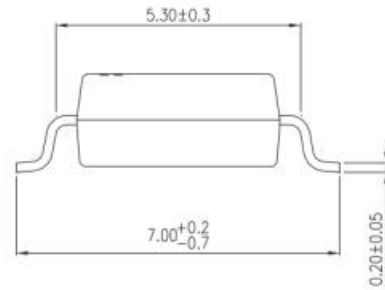
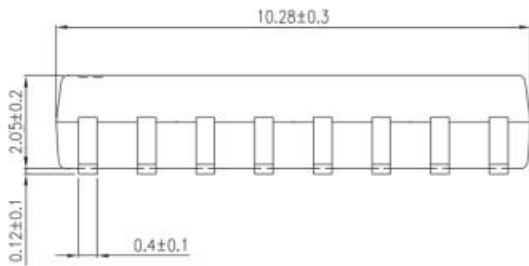
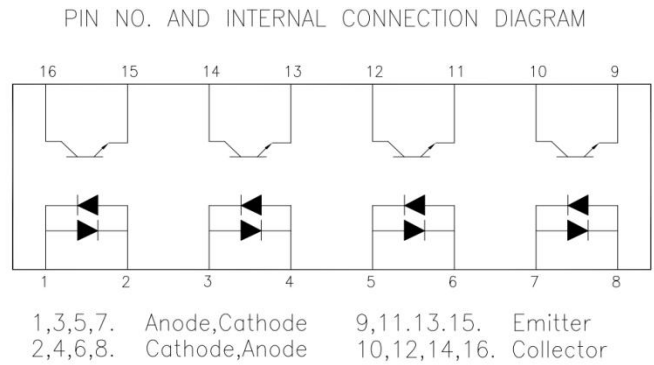
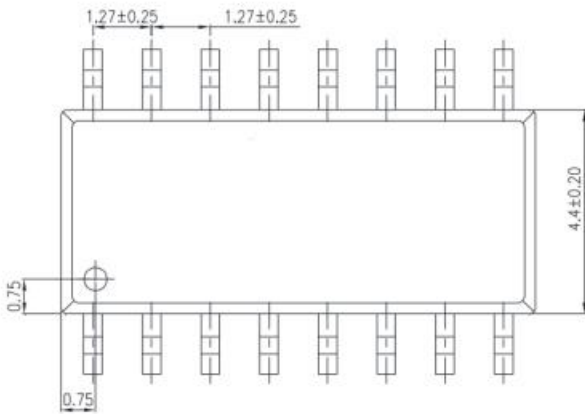
8. Naming Rule



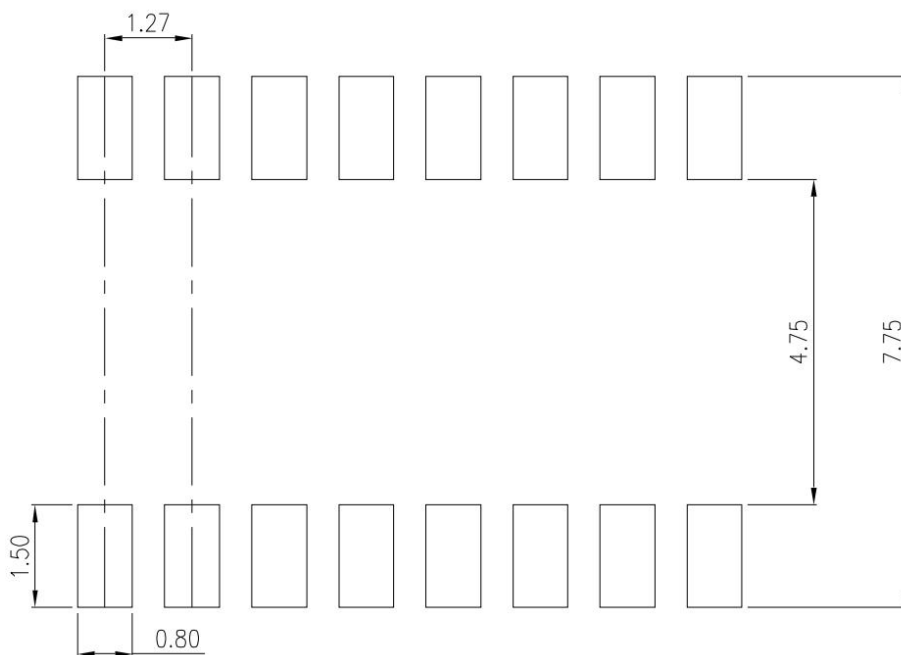
1. Manufacturer : ORIENT.
2. Part Number : 3H4-4.
3. Rank Code : CTR Rank
4. Year Code : '21' means '2021' and so on.
5. Week Code : 01 means the first week, 02 means the second week and so on.
6. VDE Code . (Optional)
7. G : Halogen Free.
8. Anode.

* VDE Mark can be selected.

9. Outer Dimension

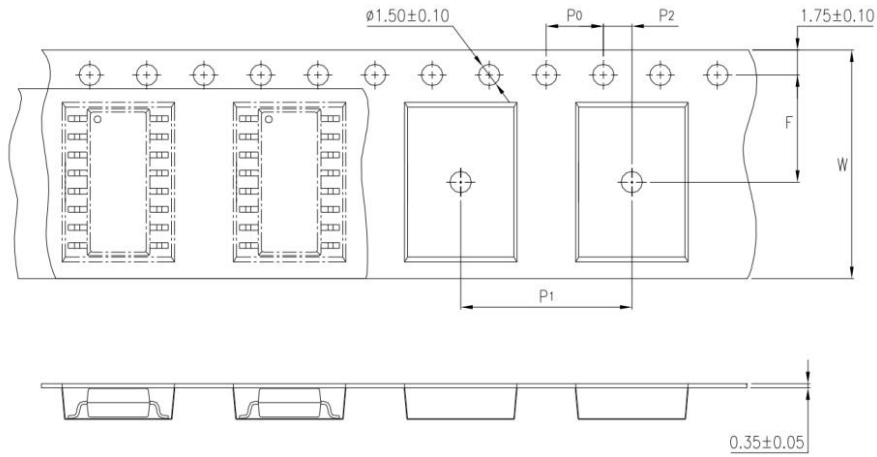


10. Recommended Foot Print Patterns (Mount Pad) (Unit:mm)

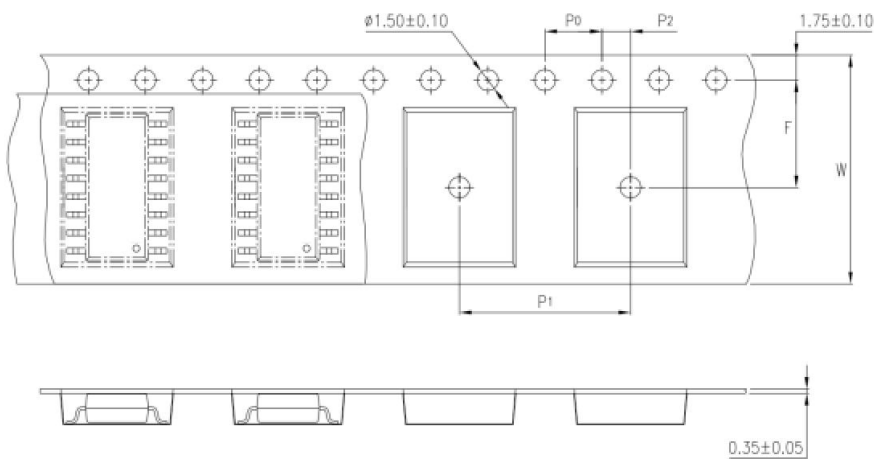


11. Taping Dimensions

(1)OR-3H4-4-TA1



(2)OR-3H4-4-TA



type	Symbol	Dimensions: mm (in.)
bandwidth	W	16±0.3 (0.47)
pitch	P0	4±0.1 (0.15)
pitch	F	7.5±0.1 (0.217)
	P2	2±0.1 (0.079)
interval	P1	12±0.1 (0.315)

Encapsulation type	TA1/TA
Quantity (pieces)	2000

12. Package Dimension

(1) package dimension

Packing Information	
Packing type	Reel type
Tape Width	16mm
Qty per Reel	2,000pcs
Small box (inner) Dimension	345*345*58.5mm
Large box (Outer) Dimension	620x360x360mm
Max qty per small box	4,000pcs
Max qty per large box	40,000pcs

(2)Packing Label Sample



Material Code : 120PCXXXXXX
|||||
P/N : OR-XXXXXX
|||||
Lot No. : XXXXXX-XXXXX-TX-X
|||||
D/C : XXXX
|||||
Qty : XXXX PCS
|||||





内箱码

外箱码

“XXXXXXXXXXXXXXXXXX” (一体机序列码)
Made in China

Note :

1. Material Code :Product ID.
2. P/N :Contents with "Order Information" in the specification.
3. Lot No. :Product data.
4. D/C :Product weeks.
5. Quantity :Packaging quantity.

13. Reliability Test

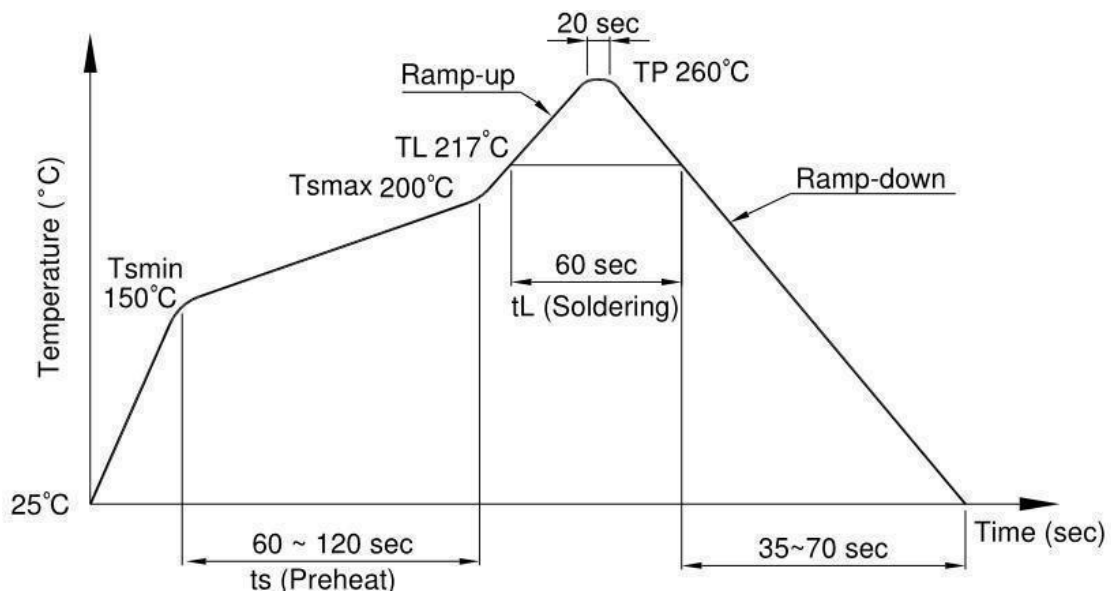
NO.	ITEMS	Reliability Testing				
		QTY. (Pcs)	Condition	Process	Device	Standard
1	RSH 耐焊接热	22	260±5℃	10s/3 次	锡炉	JESD22-A106
2	HTSL 高温存储	77	125℃	168 hrs	高温烤箱 测试仪	JESD22-A103
				500 hrs		
				1000 hrs		
3	LTSL 低温存储	77	-55℃	168 hrs	低温箱 测试仪	JESD22-A119
				500 hrs		
				1000 hrs		
4	TC 温度循环	77	H:125℃ 15min ∫ 5min L:-55℃ 15min	300 cycle	冷热冲击机	JESD22-A104
5	TS 温度冲击	77	H:100℃ 5min ∫ 15s L:-40℃ 5min	300 cycle	冷热冲击机	JESD22-A106
6	HTOL 高温操作	77	110℃ IF=10mA Vce=5V	168 hrs	高温烤箱 测试仪、老 化电路板	JESD22-A108
				500 hrs		
				1000 hrs		
7	ESD-HBM 人体模式	22	≥8KV 1Cycle	1次	ESD静电测 试仪	JESD22-A114
8	SD 可焊性	22	Pb-free 245±5℃	5S/1次	锡炉	JESD22-B102
9	HTRB 高温反向偏压	77	HTRB @125℃ Vce=80v	168 hrs	高温烤箱 , 测试仪	JESD22-A103
				500 hrs		
				1000 hrs		
10	H3TRB 温湿度反向偏 压, 寿命试验	77	H3TRB 85℃,85%RH Vce=80v	168 hrs	恒温恒湿 机, 测试仪	JESD22-A101
				500 hrs		
				1000 hrs		
11	Autoclave 压力锅	77	Ta=121 ℃,100%RH,2atm	96hrs	压力锅	JESD22-A102

14. Temperature Profile Of Soldering

(1) IR Reflow soldering (JEDEC-STD-020C compliant)

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.

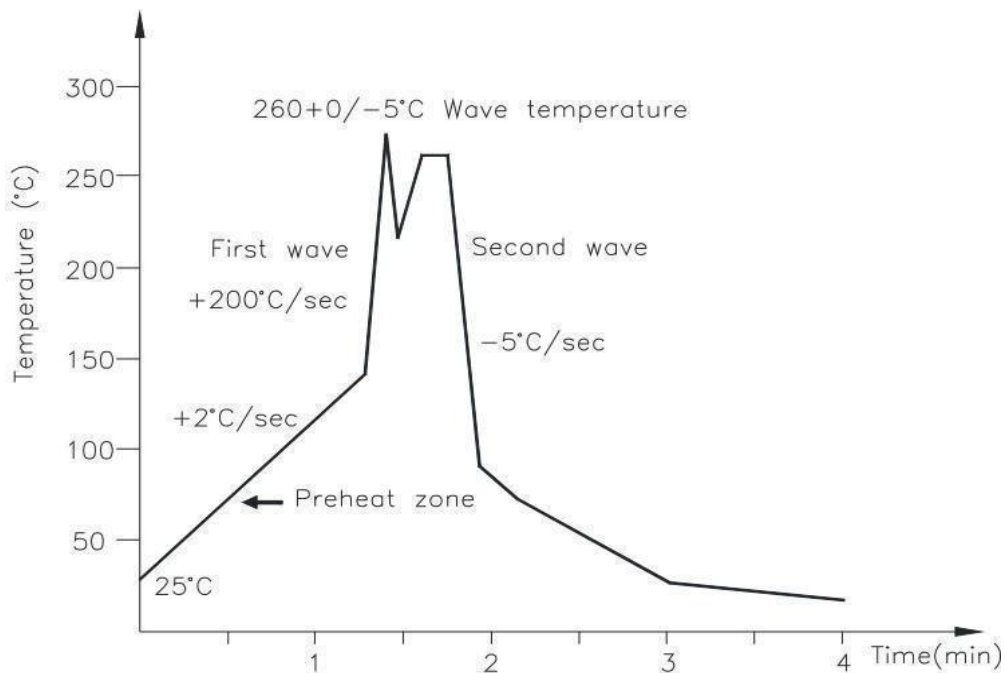
Profile item	Conditions
Preheat	
- Temperature Min (T Smin)	150°C
- Temperature Max (T Smax)	200°C
- Time (min to max) (ts)	90±30 sec
Soldering zone	
- Temperature (TL)	217°C
- Time (t L)	60 sec
Peak Temperature	260°C
Peak Temperature time	20 sec
Ramp-up rate	3°C / sec max.
Ramp-down rate from peak temperature	3~6°C / sec
Reflow times	≤3



(2) Wave soldering (JEDEC22A111 compliant)

One time soldering is recommended within the condition of temperature.

Temperature	260+0/-5°C
Time	10 sec
Preheat temperature	25 to 140°C
Preheat time	30 to 80 sec



(3) Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended.

Temperature	380+0/-5°C
Time	3 sec max

1 · Characteristics Curve

Figure 1. Collector Power Dissipation vs. Ambient Temperature

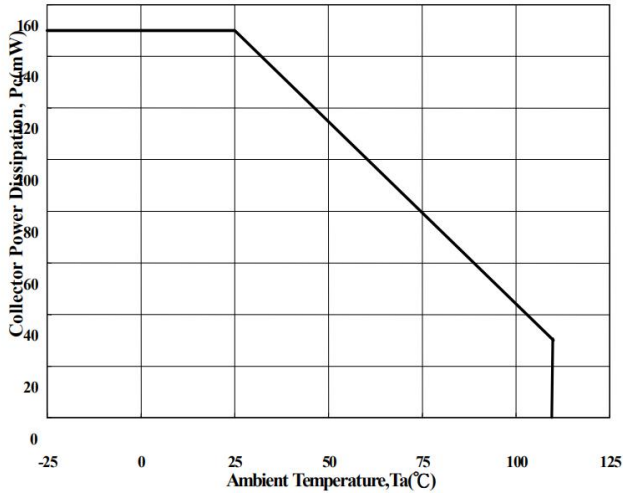


Figure 2. Forward Current vs. Ambient Temperature

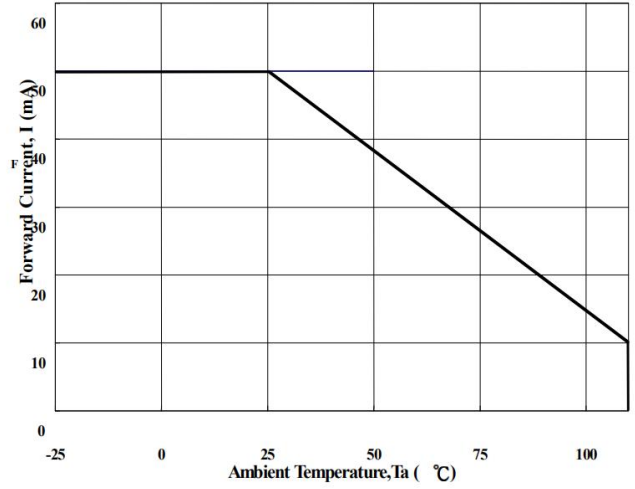


Figure 3. Forward Current vs. Forward Voltage

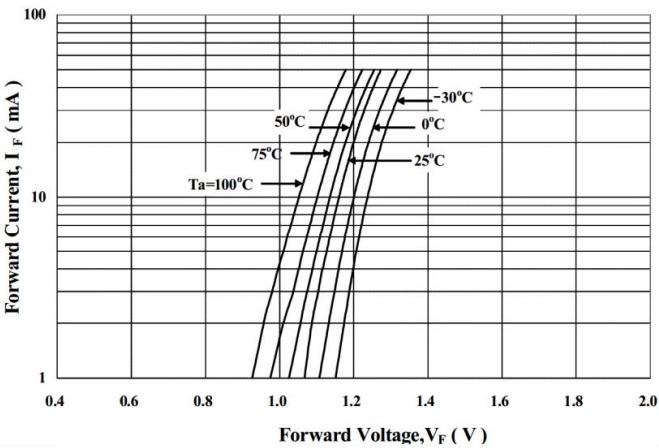


Figure 4. Forward Voltage Temperature Coefficient vs. Forward Current

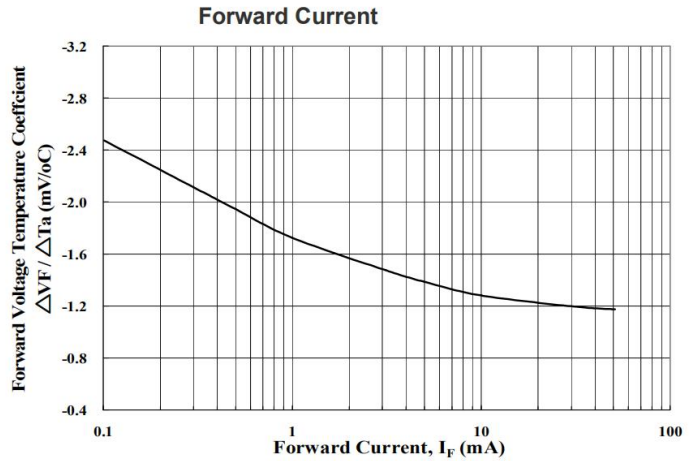


Figure 5. Pulse Forward Current vs. Duty Cycle Ratio

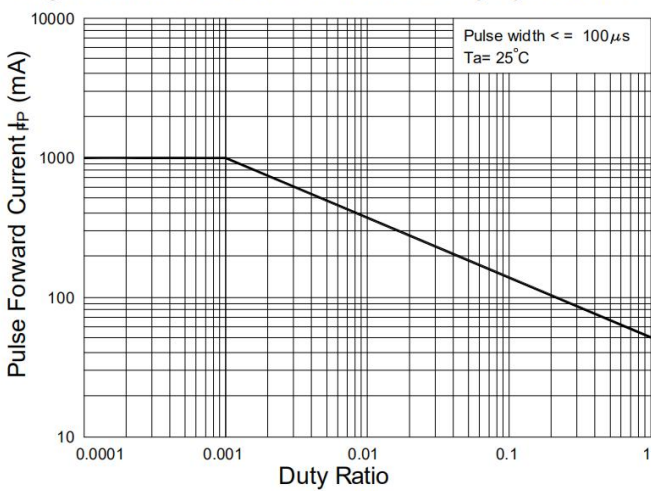


Figure 6. Pulse Forward Current vs. Pulse Forward Voltage

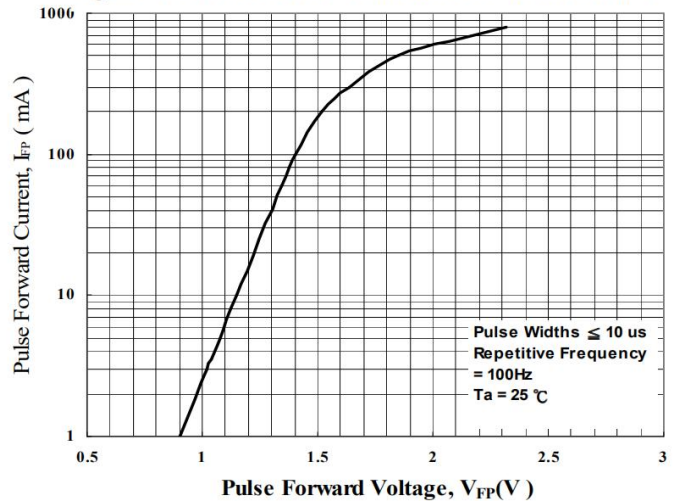


Figure 7. Collector-Emittor Saturation Voltage vs. Forward

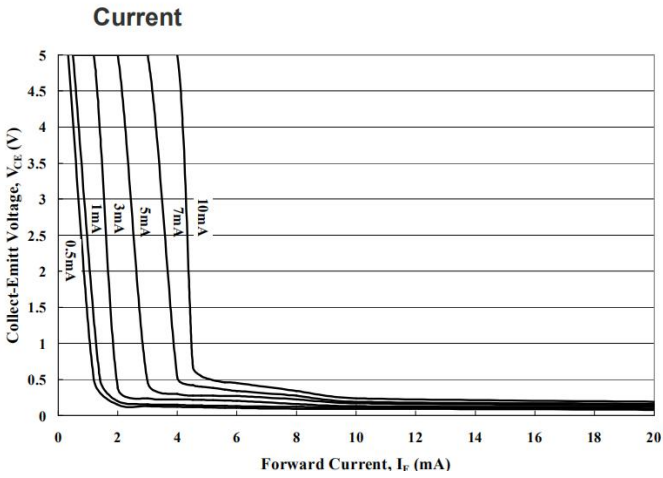


Figure 8. Collector Current vs. Collector-Emittor

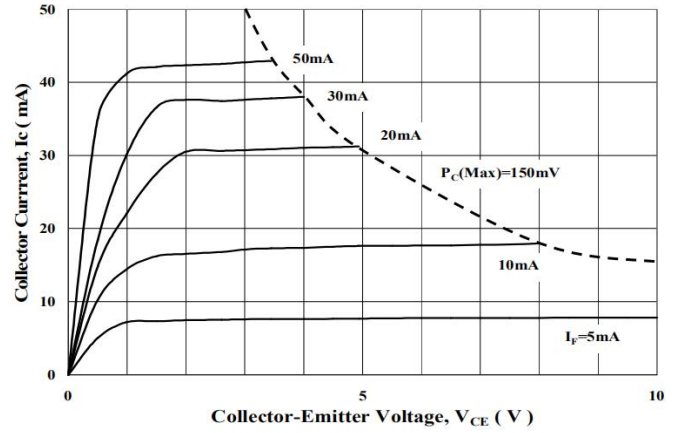


Figure 9. Collector Current vs. Small Collector-Emittor

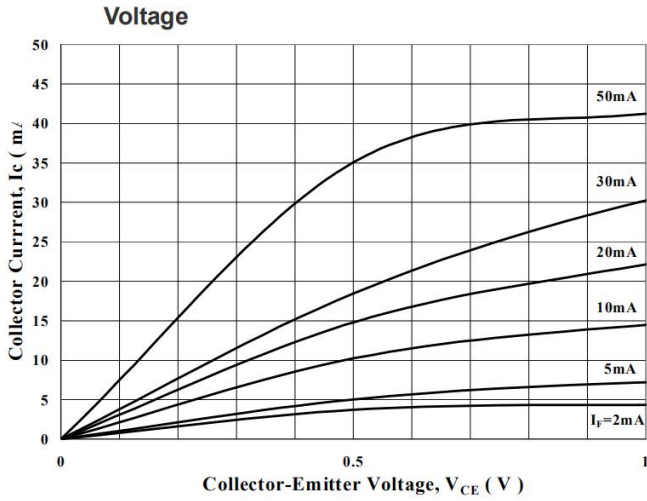


Figure 10. Normalized CTR vs. Forward Current

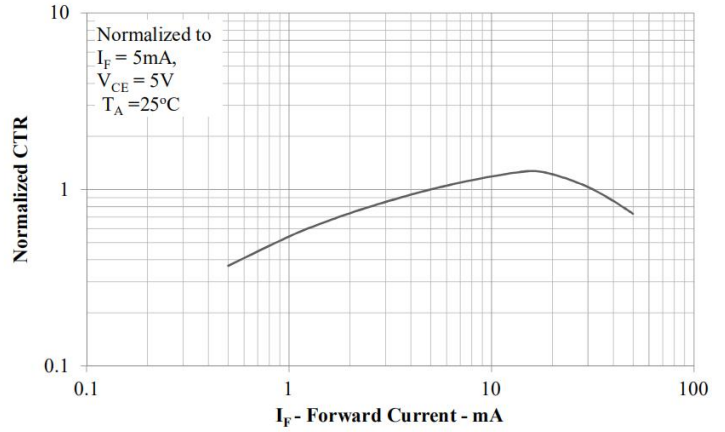


Figure 11. Collector Dark Current vs. Ambient Temperature

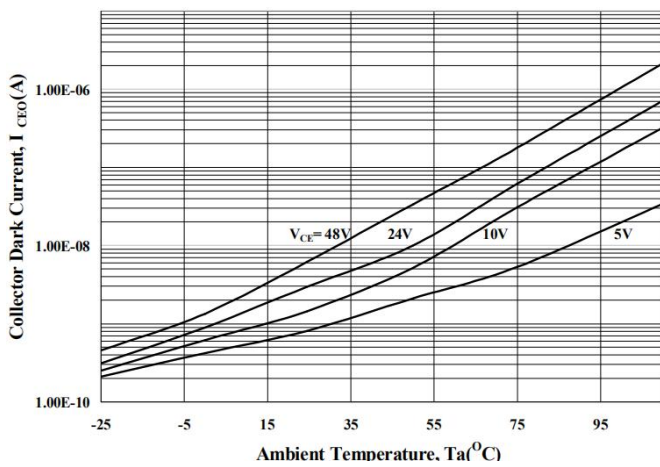


Figure 12. Current Transfer Ratio vs. Forward

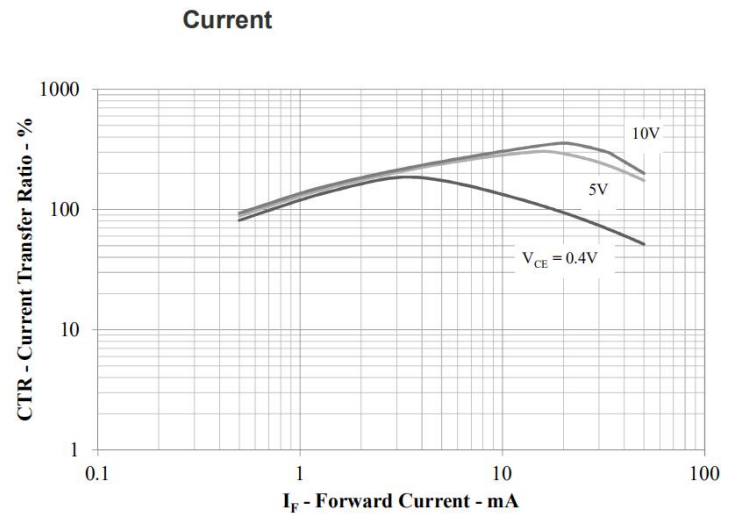


Figure 13. Normalized CTR vs. Ambient Temperature

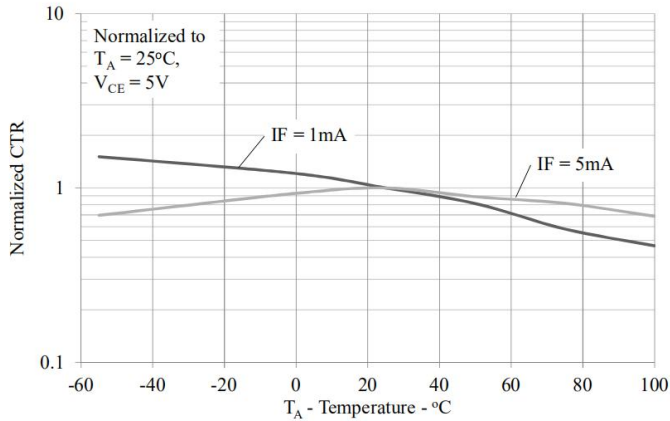


Figure 14. Collector-Emitter Saturation Voltage vs. Ambient Temperature

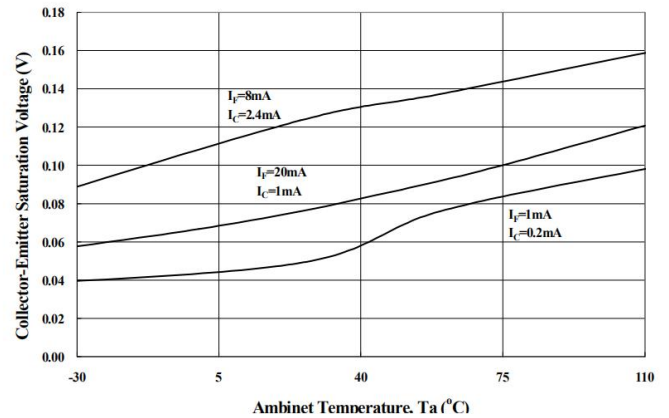


Figure 15. Collector Current vs. Ambient Temperature

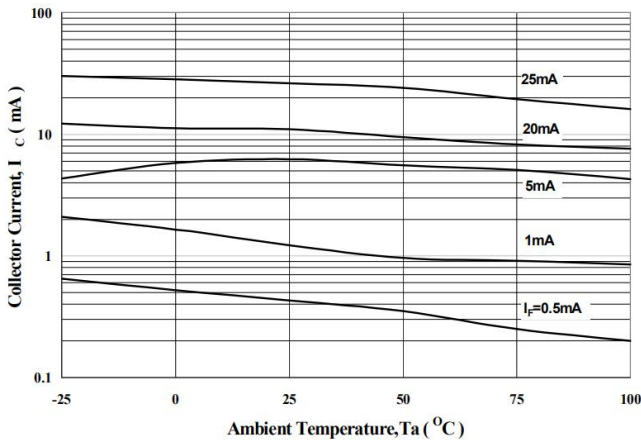


Figure 16. Switching Time vs. Load Resistance

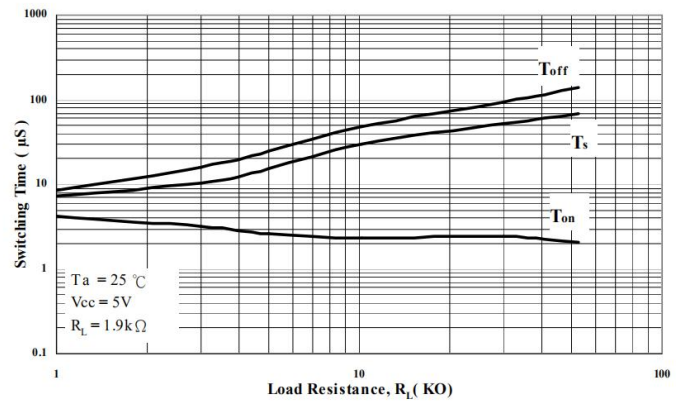


Figure 17. Switching Time vs. Ambient Temperature

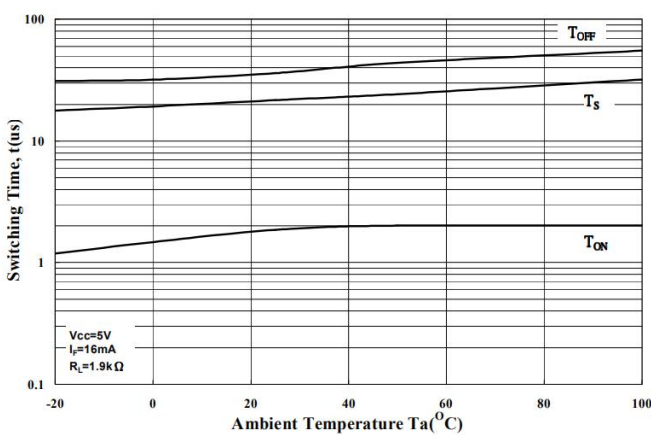


Figure 18. Frequency Response

